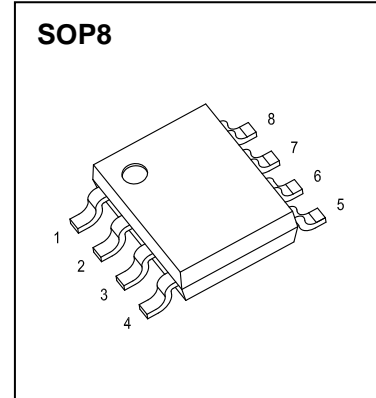




SOP8 Plastic-Encapsulate MOSFETS

ZSQ16P03 P-Channel Power MOSFET

$V_{(BR)DSS}$	$R_{DS(on)TYP}$	I_D
-30 V	5.1mΩ@-10V	-16A
	8.1mΩ@-4.5V	



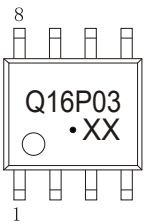
DESCRIPTION

The ZS Q16P03 combines advanced trench MOSFET technology with a low resistance package to provide extremely low $R_{DS(ON)}$. This device is ideal for load switch and battery protection applications

APPLICATIONS

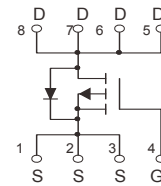
- Battery protection applications
- Load switch

MARKING



Q16P03 = Device code.
 Solid dot = Green molding compound device,
 if none, the normal device.
 XX = Code.

Equivalent Circuit



MAXIMUM RATINGS ($T_a=25^{\circ}C$ unless otherwise noted)

Parameter	Symbol	Limit	Unit
Drain-Source Voltage	V_{DS}	-30	V
Gate-Source Voltage	V_{GS}	±20	V
Continuous Drain Current	I_D ①	-16	A
Pulsed Drain Current	I_{DM} ②	-64	A
Single Pulsed Avalanche Energy	E_{AS} ③	80	mJ
Power Dissipation	P_D ⑥	3.0	W
Thermal Resistance from Junction to Ambient	$R_{\theta JA}$ ⑥	41.7	$^{\circ}C/W$
Operating Junction and Storage Temperature Range	T_J, T_{stg}	-55~+150	$^{\circ}C$

MOSFET ELECTRICAL CHARACTERISTICS

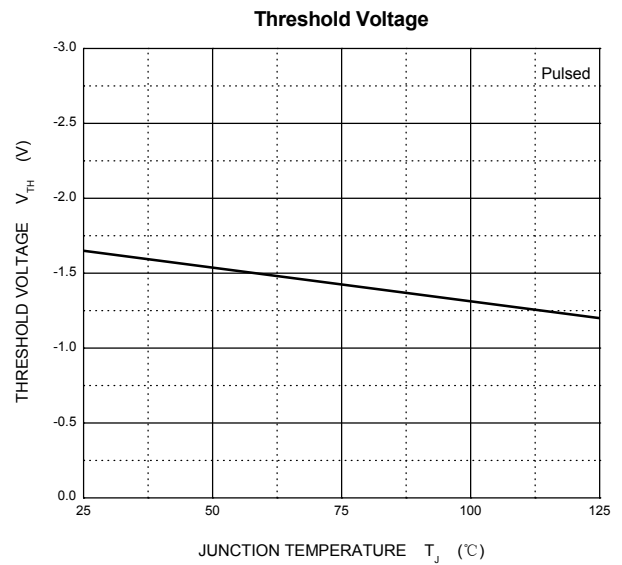
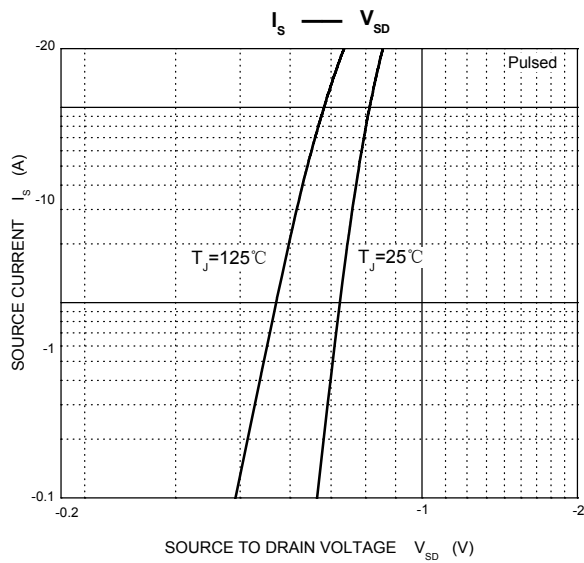
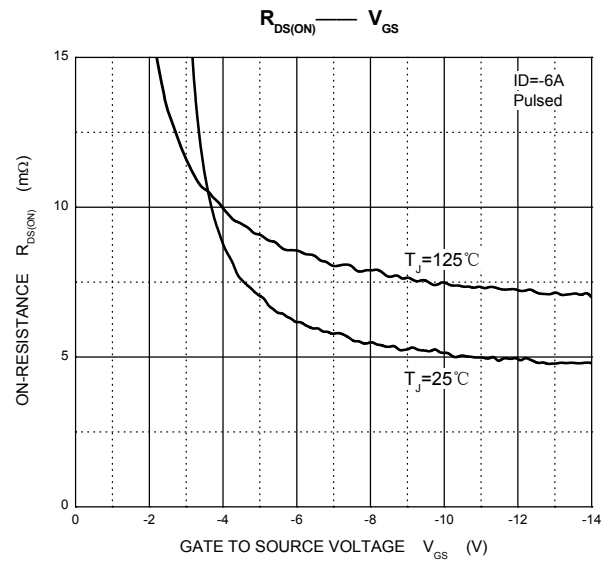
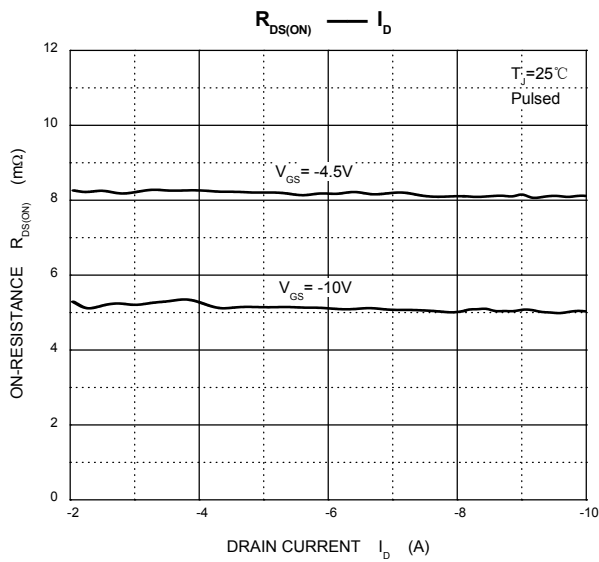
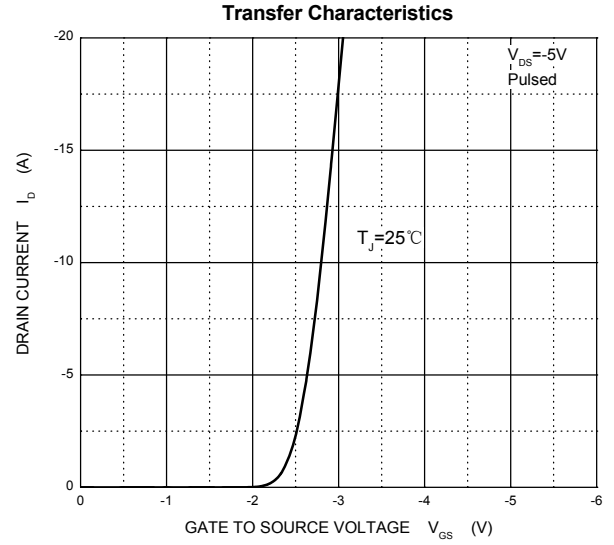
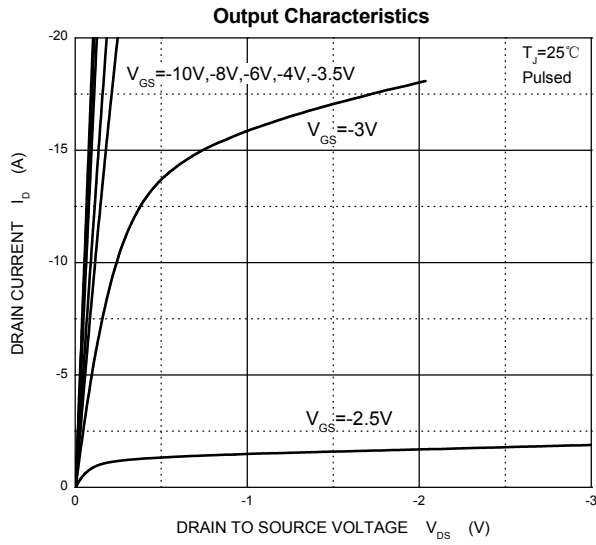
$T_a=25^\circ\text{C}$ unless otherwise specified

Parameter	Symbol	Test Condition	Min	Typ	Max	Unit
Off characteristics						
Drain-source breakdown voltage	$V_{(BR)DSS}$	$V_{GS} = 0V, I_D = -250\mu A$	-30			V
Zero gate voltage drain current	I_{DSS}	$V_{DS} = -24V, V_{GS} = 0V$	$T_J = 25^\circ\text{C}$		-1.0	μA
			$T_J = 125^\circ\text{C}$		-100	
Gate-body leakage current	I_{GSS}	$V_{DS} = 0V, V_{GS} = \pm 20V$			± 100	nA
On characteristics ④						
Gate-threshold voltage	$V_{GS(th)}$	$V_{DS} = V_{GS}, I_D = -250\mu A$	-1.0	-1.65	-2.5	V
Static drain-source on-state resistance	$R_{DS(on)}$	$V_{GS} = -10V, I_D = -6A$		5.1	6.5	m Ω
		$V_{GS} = -4.5V, I_D = -5A$		8.1	10	m Ω
Forward transconductance	g_{FS}	$V_{DS} = -5V, I_D = -14A$	10			S
Dynamic characteristics ④⑤						
Input capacitance	C_{iss}	$V_{DS} = -24V, V_{GS} = 0V, f = 1MHz$		3900	5900	pF
Output capacitance	C_{oss}			500	900	
Reverse transfer capacitance	C_{rss}			385	650	
Gate resistance	R_g	$f = 1MHz$		7.4		Ω
Switching characteristics ④⑤						
Total gate charge	Q_g	$V_{GS} = -10V, V_{DS} = -24V, I_D = -8A$		69	100	nC
Gate-source charge	Q_{gs}			21	40	
Gate-drain charge	Q_{gd}			12	20	
Turn-on delay time	$t_{d(on)}$	$V_{DS} = -15V, I_D = -1A, V_{GS} = -10V, R_G = 3.3\Omega$		38		ns
Turn-on rise time	t_r			16		
Turn-off delay time	$t_{d(off)}$			245		
Turn-off fall time	t_f			90		
Drain-Source Diode Characteristics						
Drain-source diode forward voltage	V_{SD} ④	$V_{GS} = 0V, I_S = -2.1A$			-1.2	V
Continuous drain-source diode forward current	I_S ①				-16	A
Pulsed drain-source diode forward current	I_{SM} ②				-64	A

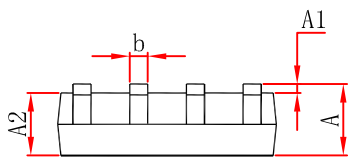
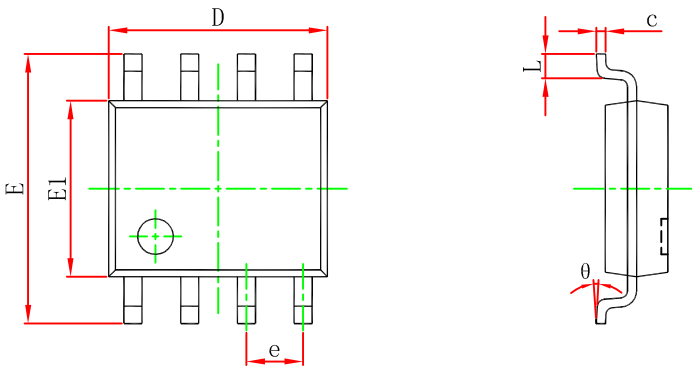
Notes:

- $T_C=25^\circ\text{C}$ Limited only by maximum temperature allowed.
- $P_W \leq 10\mu s$, Duty cycle $\leq 1\%$.
- EAS condition: $V_{DD} = -15V, V_{GS} = -10V, L = 0.5mH, R_g = 25\Omega$ Starting $T_J = 25^\circ\text{C}$.
- Pulse Test : Pulse Width $\leq 300\mu s$, duty cycle $\leq 2\%$.
- Guaranteed by design, not subject to production.
- The value of $R_{\theta JA}$ is measured with the device mounted on 1 in 2 FR-4 board with 2oz. Copper, in a still air environment with $T_a = 25^\circ\text{C}, t \leq 10\text{sec}$.

Typical Characteristics

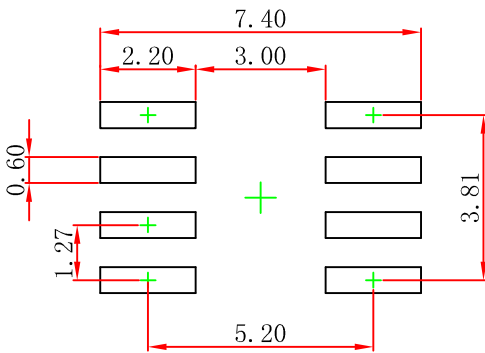


SOP8 Package Outline Dimensions



Symbol	Dimensions In Millimeters		Dimensions In Inches	
	Min	Max	Min	Max
A	1.450	1.750	0.053	0.069
A1	0.100	0.250	0.004	0.010
A2	1.350	1.550	0.053	0.061
b	0.330	0.510	0.013	0.020
c	0.170	0.250	0.007	0.010
D	4.700	5.100	0.185	0.201
e	1.270 (BSC)		0.050 (BSC)	
E	5.800	6.200	0.228	0.244
E1	3.800	4.000	0.150	0.157
L	0.400	1.270	0.016	0.050
theta	0°	8°	0°	8°

SOP8 Suggested Pad Layout

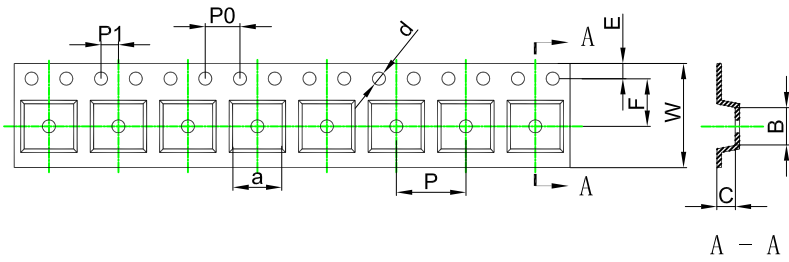


Note:

1. Controlling dimension: in millimeters.
2. General tolerance: $\pm 0.05\text{mm}$.
3. The pad layout is for reference purposes only.

SOP8 Tape and Reel

SOP8 Embossed Carrier Tape



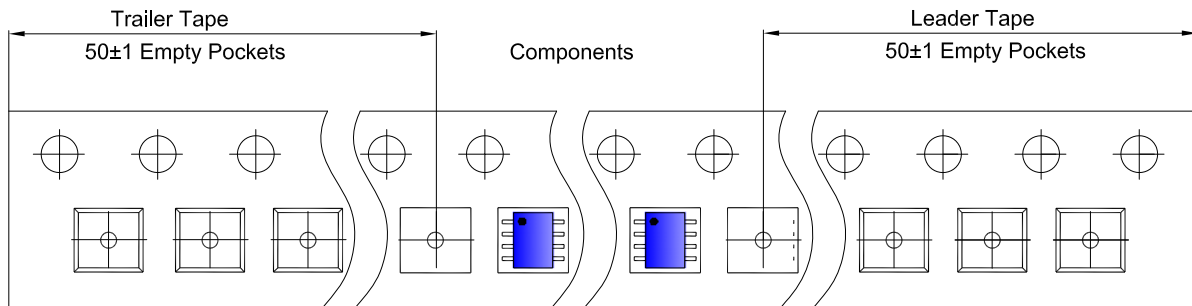
Packaging Description:

SOP8 parts are shipped in tape. The carrier tape is made from a dissipative (carbon filled) polycarbonate resin. The cover tape is a multilayer film (Heat Activated Adhesive in nature) primarily composed of polyester film, adhesive layer, sealant, and anti-static sprayed agent. These reeled parts in standard option are shipped with 4,000 units per 13" or 33cm diameter reel. The reels are clear in color and is made of polystyrene plastic (anti-static coated).

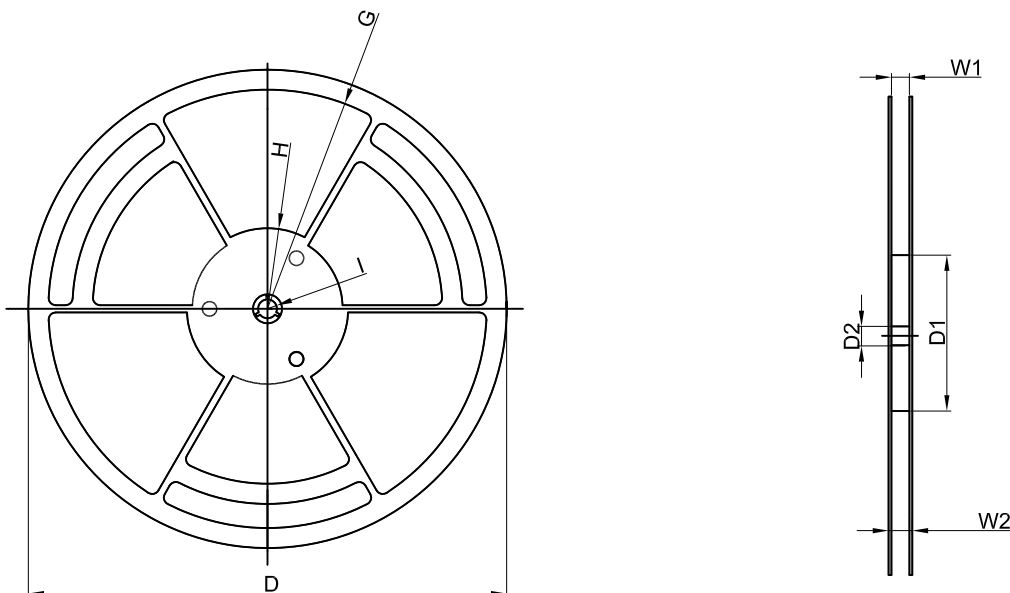
ALL DIM IN mm

Dimensions are in millimeter										
Pkg type	a	B	C	d	E	F	P0	P	P1	W
SOP8	6.40	5.40	2.10	Ø1.50	1.75	5.50	4.00	8.00	2.00	12.00

SOP8 Tape Leader and Trailer



SOP8 Reel



Dimensions are in millimeter								
Reel Option	D	D1	D2	G	H	I	W1	W2
13" Dia	Ø330.00	100.00	13.00	R151.00	R56.00	R6.50	12.40	17.60

REEL	Reel Size	Box	Box Size(mm)	Carton	Carton Size(mm)	G.W.(kg)
4,000 pcs	13 inch	8,000 pcs	360×360×65	64,000 pcs	565×380×390	